WP61065AB

High Property Device for Surge & Overvoltage noise Protection

This device has been especially designed to protect 1 low voltage or signal line, as well as classical RS-485 interface, against transient over-voltages.

ESD-voltages are clamped by 2 TVS diodes. Surges are suppressed by 2 thyristors, their breakdown voltage close to 8V,then their leakage current as low as 1uA.

This devices are not subject to ageing and provide a fail safe mode in short circuit for a better protection. WPG are used to help equipment to meet various standards such as UL1950, IEC950 / CSA C22.2, UL1459 and FCC part68.

Features

- Integrated the two TVS diodes and two thyristor
- Accurate voltage of protection
- Low switching voltages: V_{BR}
- Low leakage current: I_R = 2 uA max
- High Peak pulse current
- Solid-state silicon technology
- Meets MSL 1 Requirements
- ROHS compliant
- WeiPan technology



SMA-J

Main applications

- Signal Line
- RS-485 interface
- Telecommunications infrastructure
- PBX's and other switches
- Set-top box
- Ammeter

Ordering Information

Device	Marking	Qty per Reel	Reel Size	
WP61065AB	P065B	5000	13 Inch	



WP61065AB High Property Device for Surge & Overvoltage noise Protection Maximum ratings (Tamb=25℃ Unless Otherwise Specified) **Parameter Symbol Value** Unit Non-repetitive peak on-state current: WP61065AB 10/1000 us (Telcordia(Bellcore)Gr-1089-CORE.Issue 2.February 1999,Section4) 70 Α **I**PPSM 5/320 us (ITU-T K.20, K.21& K.45, K.44 open-circuit voltage wave shape 10/700us) 100 1.2/50 us (Telcordia(Bellcore)Gr-1089-CORE.Issue 2.February 1999,Section4) 250 Lead Soldering Temperature 260 (10 sec.) $^{\circ}$ C T_L -40 ~ 85 $^{\circ}\!\mathbb{C}$ **Operating Temperature Range** T_J Storage Temperature Range Tstg -55 ~ 150 $^{\circ}$ C $^{\circ}$ C Lead Solder Temperature - Maximum (10 Second Duration) T_L 260 Junction To ambient $R \theta JA$ 100 °C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

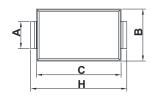
Electrical characteristics (Tamb=25°C Unless Otherwise Specified)							
	Symbol	Value					
Parameter					Unit		
		Min.	Тур.	Max.			
Repetitive peak off-state voltage,	V _{DRM}			±6.	V		
WP61065AB				5			
Leakage Current, V _R =6.5V	I _R			±2	uA		
WP61065AB	IR IR				uA		
Breakdown Voltage, I _R =1mA			±8.		V		
WP61065AB	V _{DC}		3		V		
Impulse breakover voltage, dv/dt ≤ ±100 V/µs, Linear voltage ramp,	V _{BO}			±2	V		
WP61065AB	V BO			5			
On-state voltage(Clamp Voltage), T = ± 2.2 A, t w = 100 μ s				±4	V		
WP61065AB	Vc			<u> </u>	V		
Off-state capacitance, f =1 MHz, Vd =0.3V rms, V _{DC} =2V	C _{off}			80	nE		
WP61065AB	Coff			00	pF		

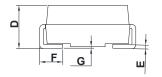
Package Information

SMA-J

Mechanical Data

- Case: SMA-J
- Case Material: Molded Plastic. UL Flammability

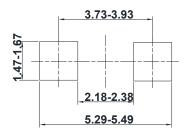




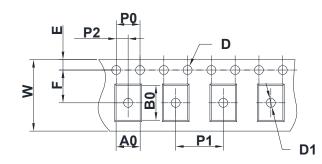


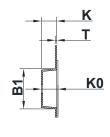
DIM	Millimeters			
	Min	Max		
A	1.23	1.80		
В	2.50	3.00		
C	3.90	5.10		
D	1.90	2.45		
E	0.10	0.31		
F	0.75	1.52		
G	0.00	0.203		
Н	4.80	5.30		

Recommended Pad outline



SMA-J Reel Dim





Package	Chip Size (mm)	Pocket Size B0×A0×K0(mm)	Tape Width	Reel Diameter	Quantity Per Reel	P0	P1
SMA-J	5.0×2.50×2.40	5.10×2.60×2.50	12mm	330mm(13inch)	5000	4mm	4mm
D	D1	E	F	K	T	W	
1.5mm	1.0mm	1.75mm	3.5mm	2.45mm	0.5mm	12mm	



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